

TKC-DT52 Series Open Loop Mode Hall Effect Current Sensor





TKC-DT52series current sensor is an open loop device based on the measuring principle of the hall effect, with a galvanic isolation between primary and secondary circuit. It provides accurate electronic measurement of DC, AC or pulsed currents.

Electrical data (Ta=25°C±5°C, RL=10KΩ, CL=10000PF)

Type Parameter	TKC 15DT52	TKC 20DT52	TKC 30DT52	TKC 40DT52	TKC 50DT52	TKC 75DT52	TKC 80DT52	TKC 100DT52	Unit
Rated input	±15	±20	±30	±40	±50	±75	±80	±100	А
Measure range (lp)	±16.5	±22	±33	±44	±55	±82.5	±88	±110	А
Rated output	@lp=±lpn						>		
Zero voltage	@Ip=0 1/2 VCC±1%						V		
Supply voltage	+5±5%						V		
Power Consumption	≤10						mA		
Zero offset voltage	≤±20							mV	
Magnetic offset voltage	±15 ±10							mV	
Offset voltage drift	≤±1.2	≤±1						mV/°C	
Output drift	≤±1.2	≤±1.2 ≤±1						mV/°C	
Linearity	@lp=0-±lpn ≤1					%FS			
Response time	@50A/μS	, 10%-90%	6	≤0.5					
Band- width	@-3dB DC-25						KHz		
Galvanic isolation	@ 50HZ, AC,1min 2.5						KV		

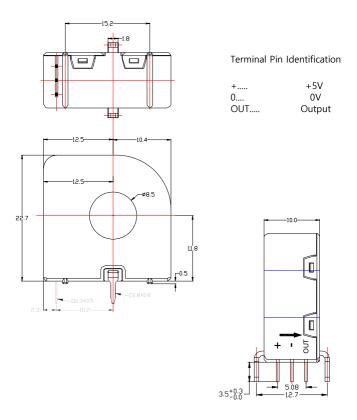
TKC-DT52 Series Open Loop Mode Hall

Effect Current Sensor

Applications

- AC variable speed drives
- Static converters for DC motor drives
- Variable speed drives
- Power supplies for welding applications
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)

Mechanical dimension (for reference only)



Remarks:

- 1. All dimensions are in mm.
- 2. General tolerance ±1mm

Directions for use

- 1. When the current will be measured goes through a sensor, the voltage will be measured at the output end. (Note: The false wiring may result in the damage of the sensor)
- 2. Customs can adjust the output amplitude of the sensor by needs.
- 3. Custom design in the different rated input current and the output voltage are available.



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Standards

UL94-V0

EN60947-1:2004

IEC60950-1:2001

EN50178:1998

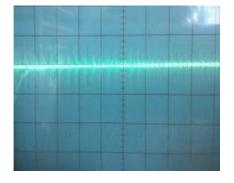
SJ 20790-2000

General data

	Value	Unit	Symbol
Operating temperature	-40 to +105	°C	TA
Storage temperature	-50 to +150	°C	TS
Mass(approx)	10	g	М

Characteristics chart

Effects of impulse noise



Input current-Output Voltage characteristic

